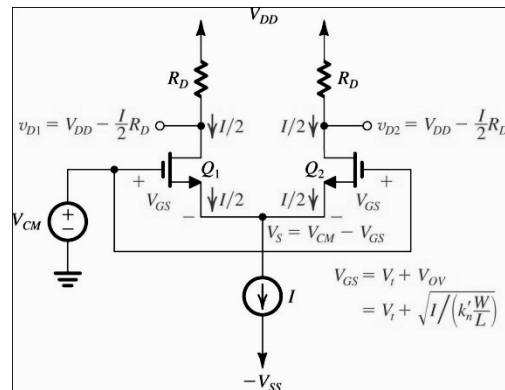


Examples #4

1. For the MOS differential pair with a common-mode voltage V_{CM} applied, as shown below, let $V_{DD}=V_{SS}=1V$, $k_n'=0.4mA/V^2$, $(W/L)_{1,2}=12.5$, $V_t=0.5V$, $I=0.2mA$, and $R_D=10k\Omega$ (neglect channel-length modulation). Assume that the current source I requires a minimum voltage of $0.4V$ to operate properly. (worth 2 problems)

- Find V_{GS} for each transistor.
- For $V_{CM}=0$ find V_{S1} , I_{D1} , I_{D2} , V_{D1} , and V_{D2} .
- Repeat (b) for $V_{CM}=0.3V$.
- Repeat (b) for $V_{CM}=-0.1V$.
- What is the highest permitted value of V_{CM} for which $Q1$ and $Q2$ remain in saturation?
- If the current source requires a minimum of $0.2V$ across it to operate correctly, what is the lowest value allowed for V_S and hence for V_{CM} ?



note that $I_{D1} = I_{D2} = \frac{I}{2} = \frac{0.2 \text{ mA}}{2}$
 $= 0.1 \text{ mA}$

$$I_D = \frac{1}{2} k_n' \left(\frac{W}{L} \right) V_{ov}^2$$

$$V_{ov} = \sqrt{\frac{2I_D}{k_n' (W/L)}} = \sqrt{\frac{2(0.1 \text{ mA})}{0.4 \text{ mA/V}^2 (12.5)}}$$

$$= 0.2 \text{ V}$$

$$V_{GS} = V_{nt} + V_{ov} = 0.5 + 0.2 = 0.7 \text{ V}$$

(b) If $V_{cm} = 0$,

$$V_{s1} = V_{s2} = V_G - V_{GS} = 0 - 0.7 = -0.7 \text{ V}$$

$$I_{D1} = I_{D2} = \frac{0.2 \text{ mA}}{2} = 0.1 \text{ mA}$$

$$V_{D1} = V_{D2} = V_{DD} - I_{D1} R_D$$

$$= 1V - (0.1 \text{ mA})(10 \text{ K}) = 0 \text{ V}$$

(c) Now, if $V_{ICM} = 0.1 \text{ V}$,

$$V_{s1} = V_{s2} = V_C - V_{GS} = 0.1 \text{ V} - 0.7 \text{ V}$$

$$= -0.6 \text{ V}$$

Since I is a constant current source,
 I_{D1} and I_{D2} remain at 0.1 mA
 This means that
 V_{D1} and V_{D2} are still 0 V

(d) $V_{ICM} = -0.1 \text{ V}$,

$$V_{s1} = V_{s2} = V_G - V_{GS} = -0.1 \text{ V} - 0.7$$

$$= -0.8 \text{ V}$$

Still, $I_{D1} = I_{D2} = 0.1 \text{ mA}$
 $V_{D1} = V_{D2} = 0 \text{ V}$

(e) $V_{cm}(\text{max}) = V_{DD} - I_D R_D - V_{ov} + V_{GS}$
 $= 1 - (0.1 \text{ mA})(10 \text{ K}) - 0.2 + 0.7 = +0.5 \text{ V}$

(f) $V_S(\text{min}) = -V_{SS} + V_{CS}(\text{min})$
 $= -1 + 0.2 = -0.8 \text{ V}$
 $V_{CM}(\text{min}) = V_S(\text{min}) + V_{GS} = -0.8 \text{ V} + 0.7 \text{ V}$
 $= -0.1 \text{ V}$

Examples #4

2. For the differential amplifier of Problem 1, let $V_{G2}=0$ and $V_{G2}=V_{id}$. Find the value of V_{id} that corresponds to each of the following situations:

(a) $i_{D1}=i_{D2}=0.1\text{mA}$; (b) $i_{D1}=0.15\text{mA}$ and $i_{D2}=0.05\text{mA}$; (c) $i_{D1}=0.2\text{mA}$ and $i_{D2}=0$ (Q2 just cuts off); (d) $i_{D1}=0.05\text{mA}$ and $i_{D2}=0.15\text{mA}$; (e) $i_{D1}=0$ (Q1 just cuts off) and $i_{D2}=0.2\text{mA}$. For each case, find v_s , v_{D1} , v_{D2} , and $(v_{D2}-v_{D1})$.

$$V_{OV} = \sqrt{\frac{2I_D}{k_n'(W/L)}} = \sqrt{\frac{2(0.1\text{ mA})}{0.4\text{ mA/V}^2(12.5)}} = 0.2\text{ V}$$

$$(a) V_{GS} = V_{OV} + V_t = 0.2\text{ V} + 0.5\text{ V} = 0.7\text{ V}$$

$$V_S = V_G - V_{GS} = 0 - 0.7\text{ V} = -0.7\text{ V}$$

$$V_{D1} = V_{D2} = V_{DD} - i_{D1}R_D = 1.0\text{ V} - 0.1\text{ mA}(10\text{ k}\Omega) = 0\text{ V}$$

$$V_{D2} - V_{D1} = 0\text{ V}$$

$$(b) \text{ For } i_{D1} = 0.15\text{ mA}, i_{D2} = 0.05\text{ mA},$$

$$i_{D1} = \frac{I}{2} + \frac{I}{V_{OV}} \cdot \frac{v_{id}}{2} \rightarrow v_{id} = \left(\frac{2i_{D1}}{I} - 1 \right) \cdot V_{OV}$$

$$v_{id} = \left[\frac{2(0.15\text{ mA})}{0.2\text{ mA}} - 1 \right] (0.2\text{ V}) = 0.1\text{ V}$$

$$V_{GS1} = \sqrt{\frac{2(0.15\text{ mA})}{0.4\text{ mA/V}^2(12.5)}} + 0.5\text{ V} = 0.745\text{ V}$$

$$V_S = V_G - V_{GS1} = 0.1\text{ V} - 0.745\text{ V} = -0.645\text{ V}$$

$$V_{D1} = V_{DD} - i_{D1}R_D = 1.0\text{ V} - 0.15\text{ mA}(10\text{ k}\Omega) = -0.5\text{ V}$$

$$V_{D2} = 1.0\text{ V} - (0.05\text{ mA})(10\text{ k}\Omega) = +0.5\text{ V}$$

$$V_{D2} - V_{D1} = 1.0\text{ V}$$

$$(c) i_{D1} = 0.2\text{ mA}, i_{D2} = 0:$$

$$V_{G1} = v_{id} = \sqrt{2} \cdot V_{OV} = 1.414(0.2\text{ V}) = 0.283\text{ V}$$

$$V_{GS} = \sqrt{\frac{2(0.2\text{ mA})}{0.4\text{ mA/V}^2(12.5)}} + 0.5\text{ V} = 0.783\text{ V}$$

$$V_S = V_G - V_{GS} = 0.283\text{ V} - 0.783\text{ V} = -0.5\text{ V}$$

$$V_{D1} = 1.0\text{ V} - (0.2\text{ mA})(10\text{ k}\Omega) = -1.0\text{ V}$$

$$V_{D2} = +1.0\text{ V}$$

$$V_{D2} - V_{D1} = 2.0\text{ V}$$

$$(d) \left. \begin{array}{l} i_{D1} = 0.05\text{ mA} \\ i_{D2} = 0.05\text{ mA} \end{array} \right\} \text{opposite case of (b)}$$

For example,

$$v_{id} = \left[\frac{2(0.05\text{ mA})}{0.2\text{ mA}} - 1 \right] (0.2\text{ V}) = -0.1\text{ V}$$

$$V_{GS} = \sqrt{\frac{2(0.05\text{ mA})}{0.4\text{ mA/V}^2(12.5)}} + 0.5\text{ V} = 0.641\text{ V}$$

$$V_S = V_G - V_{GS} = -0.1\text{ V} - 0.641\text{ V} = -0.741\text{ V}$$

$$V_{D1} = 1.0\text{ V} - (0.05\text{ mA})(10\text{ k}\Omega) = +0.5\text{ V}$$

$$V_{D2} = 1.0\text{ V} - (0.05\text{ mA})(10\text{ k}\Omega) = -0.5\text{ V}$$

$$V_{D2} - V_{D1} = -1.0\text{ V}$$

(e) $i_{D1} = 0\text{ mA}$, $i_{D2} = 0.2\text{ mA}$ is the opposite of (c):

$$v_{id} = -\sqrt{2}(V_{OV}) = -\sqrt{2}(0.2\text{ V}) = -0.283\text{ V}$$

For $i_{D2} = 0.2\text{ mA}$, $V_{GS2} = 0.783\text{ V}$, So that

$$V_S = -0.783\text{ V}$$

$$V_{D1} = 1.0\text{ V},$$

$$V_{D2} = -1.0\text{ V} \rightarrow V_{D2} - V_{D1} = -2\text{ V}$$

The results are summarized in the following table:

Case	V_{id} (V)	i_{D1} (mA)	i_{D2} (mA)	V_S (V)	V_{D1} (V)	V_{D2} (V)	$V_{D2} - V_{D1}$ (V)
(a)	0	0.1	0.1	-0.7	0	0	0
(b)	0.1	0.15	0.05	-0.645	-0.5	0.5	1.0
(c)	0.283	0.2	0	-0.5	-1.0	1.0	2.0
(d)	-0.1	0.05	0.15	-0.741	0.5	-0.5	-1.0
(e)	-0.283	0	0.2	-0.783	1.0	-1.0	-2.0

Examples #4

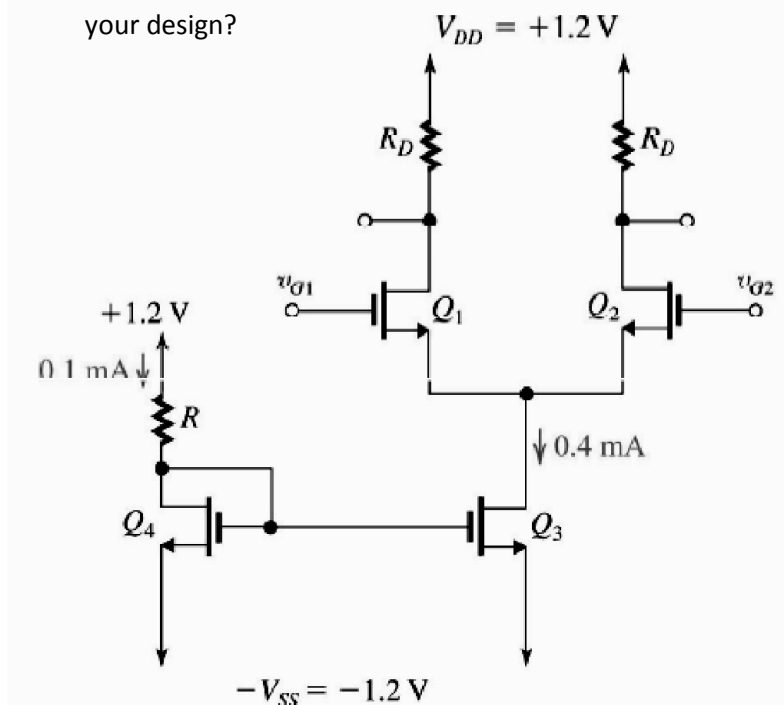
3. Consider the differential amplifier specified in Problem 1 with G_2 grounded and $V_{G1} = V_{id}$. Let V_{id} be adjusted to the value that causes $i_{D1} = 0.11 \text{ mA}$ and $i_{D2} = 0.09 \text{ mA}$. Find the corresponding values of V_{GS2} , V_S , V_{GS1} , and hence V_{id} . What is the difference output voltage ($V_{D2} - V_{D1}$)? What is the voltage gain ($(V_{D2} - V_{D1})/V_{id}$)? What value of V_{id} results in $i_{D1} = 0.09 \text{ mA}$ and $i_{D2} = 0.11 \text{ mA}$?

$$\begin{aligned}
 V_{G1} &= v_{id} \quad i_{D1} = 0.11 \text{ mA} \\
 V_{G2} &= 0 \quad i_{D2} = 0.09 \text{ mA} \\
 I_D &= \frac{1}{2} k'_n \frac{W}{L} (V_{GS} - V_t)^2 \\
 \text{For } Q_1: \\
 0.11 \text{ mA} &= \frac{1}{2} 5 \text{ m} (V_{GS1} - 0.5)^2 \\
 \rightarrow V_{GS1} &= 0.71 \text{ V} \\
 \text{For } Q_2: \\
 0.09 \text{ mA} &= \frac{1}{2} 5 \text{ m} (V_{GS2} - 0.5)^2 \\
 \rightarrow V_{GS2} &= 0.69 \text{ V} \\
 V_S &= -V_{GS2} = -0.69 \text{ V} \\
 v_{id} &= V_S + V_{GS1} = -0.69 + 0.71 \\
 &= 0.02 \text{ V}
 \end{aligned}$$

$$\begin{aligned}
 V_{D2} - V_{D1} &= 10 \text{ k}\Omega (i_{D1} - i_{D2}) \\
 &= 10 \text{ kV} (0.11 - 0.09) \text{ mA} \\
 &= 0.2 \text{ V} \\
 \text{thus} \\
 \frac{V_{D2} - V_{D1}}{v_{id}} &= \frac{0.2}{0.02} = 10 \\
 \text{when } i_{D1} &= 0.09 \text{ mA and} \\
 i_{D2} &= 0.11 \text{ mA} \\
 \text{is the reverse condition from the case we just} \\
 \text{studied, thus } v_{id} &= -0.02 \text{ V}
 \end{aligned}$$

Examples #4

4. Design the circuit shown below to obtain a dc voltage of +2V at each of the drains of Q1 and Q2 when $V_{G1}=V_{G2}=0V$. Operate all transistors at $V_{OV}=0.2V$ and assume that for the process technology in which the circuit is fabricated, $V_{tn}=0.5V$ and $k_n'=250\mu A/V^2$. Neglect channel-length modulation. Determine the values of R , R_D , and the W/L ratios of Q1, Q2, Q3, and Q4. What is the input common-mode range for your design?



$$\begin{aligned}
 V_{GS} &= V_{tn} + V_{OV} = 0.5 \text{ V} + 0.2 \text{ V} = 0.7 \text{ V} \\
 V_{D4} &= V_{G4} = -V_{S4} + V_{GS} = -1.2 \text{ V} + 0.7 \text{ V} = -0.5 \text{ V} \\
 R &= \frac{V_{DD} - V_{D4}}{0.1 \text{ mA}} = \frac{1.2 \text{ V} - (-0.5 \text{ V})}{0.1 \text{ mA}} = 17 \text{ k}\Omega \\
 R_D &= \frac{V_{DD} - V_{D1}}{0.4 \text{ mA} / 2} = \frac{1.2 \text{ V} - 0.2 \text{ V}}{0.2 \text{ mA}} = 5 \text{ k}\Omega \\
 \left(\frac{W}{L}\right)_1 &= \left(\frac{W}{L}\right)_2 = \frac{0.4 \text{ mA}}{2} \left[\frac{k'_n V_{OV}^2}{2} \right]^{-1} = 20 \\
 \left(\frac{W}{L}\right)_3 &= 0.4 \text{ mA} [0.01 \text{ mA}]^{-1} = 40 \\
 \left(\frac{W}{L}\right)_4 &= 0.1 \text{ mA} [0.01 \text{ mA}]^{-1} = 10 \\
 V_{Cm(max)} &= V_{tn} + V_{DD} - (I/2)R_D = 0.5 \text{ V} + 1.2 \text{ V} - (0.2 \text{ mA})(5 \text{ k}\Omega) = 0.7 \text{ V} \\
 V_{Cm(min)} &= -V_{SS} + V_{OV3} + V_{tn} + V_{OV1} = -1.2 \text{ V} + 0.2 \text{ V} + 0.5 \text{ V} + 0.2 \text{ V} = -0.3 \text{ V}
 \end{aligned}$$

5. Design a MOS differential amplifier to operate from $\pm 1V$ power supplies and dissipate no more than 2mW in the equilibrium state. The differential voltage gain A_d is to be 5 V/V and the output common-mode dc voltage is to be 0.5V. (Note: This is the dc voltage at the drains). Assume $k_n'=400\mu A/V^2$ and neglect the Early effect. Specify the required values of I , R_D , and W/L .

$$\begin{aligned}
 &+1 \text{ V supplies not more than } 2 \text{ mW } A_d = 5 \text{ V/V} \\
 &V_D = 0.5 \text{ V } K_n' = \mu_n C_{ox} = 0.4 \text{ mA/V}^2 \\
 &I = \frac{2 \text{ mW}}{1 \text{ V} - (-1 \text{ V})} = 1 \text{ mA} \\
 &R_D = \frac{1 \text{ V} - 0.5 \text{ V}}{1/2 I} = \frac{0.5 \text{ V}}{0.5 \text{ mA}} = 1 \text{ k}\Omega \\
 &g_m = \frac{A_d}{R_D} = \frac{5 \text{ V/V}}{1 \text{ k}\Omega} = 5 \text{ mA/V} \\
 &V_{OV} = \frac{I}{g_m} = \frac{1 \text{ mA}}{5 \text{ mA/V}} = 0.2 \text{ V}
 \end{aligned}$$

$$\begin{aligned}
 \frac{W}{L} &= 2(I/2) / (k'_n V_{OV}^2) \\
 &= 1 \text{ mA} / (0.4 \text{ mA/V}^2 \cdot (0.2 \text{ V})^2) = 62.5
 \end{aligned}$$

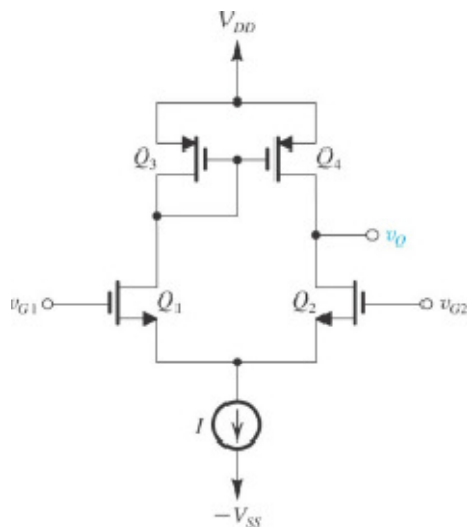
BECAUSE WE PICKED $I = 1 \text{ mA}$ THIS IS THE SOLUTION WITH THE HIGHEST ALLOWABLE POWER. THIS SOLUTION WILL ALSO THEREFORE HAVE THE WIDEST RANGE OF DIFFERENTIAL MODE OPERATION. AN INFINITE NUMBER OF OTHER SOLUTIONS EXIST.

Examples #4

6. An NMOS differential amplifier is operated at a bias current I of 0.4mA and has a W/L ratio of 32, $k_n' = \mu_n C_{ox} = 200 \mu A/V^2$, $V_A = 10V$, and $R_D = 5k\Omega$. Find $V_{ov} = (V_{GS} - V_t)$, g_m , r_o , and A_d .

$$\begin{aligned}
 I &= 0.4 \text{ mA} \quad W/L = 32 \quad k_n = \mu_n C_{ox} \\
 &= 200 \mu A / V^2 \\
 V_A &= 10 \text{ V} \quad R_D = 5 \text{ k}\Omega \\
 V_{ov}' &= \sqrt{I / k_n' \left(\frac{W}{L} \right)} = \sqrt{0.4 / (0.2 \cdot 32)} \\
 &= 0.25 \text{ V} \\
 g_m &= \frac{I}{V_{ov}} = \frac{0.4 \text{ mA}}{0.25 \text{ V}} = 1.6 \text{ mA/V} \\
 r_o &= \frac{V_A}{I_D} = \frac{10 \text{ V}}{0.2 \text{ mA}} = 50 \text{ k}\Omega \\
 A_d &= g_m (R_D \parallel r_o) = 1.6 (5 \parallel 50) \\
 &= 1.6 (4.54) = 7.3 \text{ V/V}
 \end{aligned}$$

7. An active-loaded NMOS differential amplifier operates with a bias current I of 100 μA . The NMOS transistors are operated at $V_{ov} = 0.2V$ and the PMOS dives at $|V_{ov}| = 0.3V$. The Early voltages are 20V for the NMOS and 12V for the PMOS transistors. Find G_m , R_o (output R), and A_d . For what value of load resistance is the gain reduced by a factor of 2?



$$\begin{aligned}
 I_{D1} &= I_{D2} = I_{D3} = I_{D4} = \frac{I}{2} = \frac{100 \mu A}{2} = 50 \mu A \\
 g_{m1} &= g_{m2} = \frac{I_D}{V_{ov}/2} = \frac{50 \mu A}{0.2 \text{ V}/2} = 0.5 \text{ mA/V} \\
 G_m &= g_{m1} = 0.5 \text{ mA/V} \\
 r_{o1} &= r_{o2} = \frac{V_{An}}{I_D} = \frac{20 \text{ V}}{0.05 \text{ mA}} = 400 \text{ k}\Omega \\
 r_{o3} &= r_{o4} = \frac{|V_{Ap}|}{I_D} = \frac{12 \text{ V}}{0.05 \text{ mA}} = 240 \text{ k}\Omega
 \end{aligned}$$

$$\begin{aligned}
 R_o &= r_{o2} \parallel r_{o4} = 400 \text{ k} \parallel 240 \text{ k} = 150 \text{ k}\Omega \\
 A_d &= G_m R_o = (0.5 \text{ mA/V})(150 \text{ k}) = 75 \text{ V/V} \\
 \text{Gain will be reduced by a factor of 2 if} \\
 R_L &= R_o = 150 \text{ k}\Omega
 \end{aligned}$$